

HV start-up flyback controller with integrated MOSFET for 11 W applications, 1750 Hz burst frequency

Rev. 2.1 — 7 June 2012

**Product data sheet** 

## 1. Product profile

### 1.1 General description

The TEA1723 is a small and low cost module Switched Mode Power Supply (SMPS) controller IC for power applications (up to 11 W) and operates directly from the rectified universal mains input. The device includes a high voltage power switch (700 V) and has been optimized for flyback converter topologies to provide high-efficiency over the entire load range with ultra-low power consumption in the no-load condition. It provides a circuit for start-up directly from the rectified mains voltage without any external bleeder circuits.

The converter operates as a regulated voltage source from no-load up to the maximum output current and operates as current source that delivers the maximum current over a broad output voltage range. Using the TEA1723, a low power converter can be built at minimum cost and with the minimum number of external components.

The controller regulates the output voltage with primary-side sensing which eliminates the need for an additional secondary feedback circuitry and simplifies the design. At higher power levels, a frequency and current control mode is used. It operates with burst mode control at low power levels and no-load condition. The burst mode minimizes audible noise and provides an energy saver state which reduces the power consumption in no-load condition. The Burst mode frequency of 1750 Hz enables no-load power consumption < 53 mW at 230 V (AC) mains input.

### 1.2 Features and benefits

Power features:

- Low power SMPS controller with integrated power switch designed for applications up to 11 W
- 700 V high voltage power switch for global mains operation
- Primary sensing for control of the output voltage without optocoupler and secondary feedback circuitry
- Minimizes audible noise in all operation modes
- Energy Star 2.0 compliant
- Jitter function for reduced EMI



#### HV start-up flyback controller with integrated MOSFET for 11 W

Green features:

- Enables no-load power consumption below < 53 mW</p>
- Very low supply current in no-load condition with energy saver mode
- Incorporates a high voltage start-up circuit with zero current consumption under normal switching operation
- Available in halogen-free and Restriction of Hazardous Substances (RoHS) SO7 package

Protective functions:

- OverVoltage Protection (OVP) on Feedback control (FB) pin with auto-restart
- UnderVoltage LockOut (UVLO) protection on IC supply pin
- OverTemperature Protection (OTP)
- Soft-start by reduced peak current for zero and low output voltage
- Demagnetization protection for guaranteed discontinuous conduction mode operation
- Open and short-circuit protection of the Feedback control (FB) pin
- Short-circuit protection of the charger output

### **1.3 Applications**

- Battery chargers for cellular phones, tablet pc and other power adapters up to 11 W
- Standby supply for TV, desktop PC and set-top boxes
- Power supply for white goods applications

### 1.4 Quick reference data

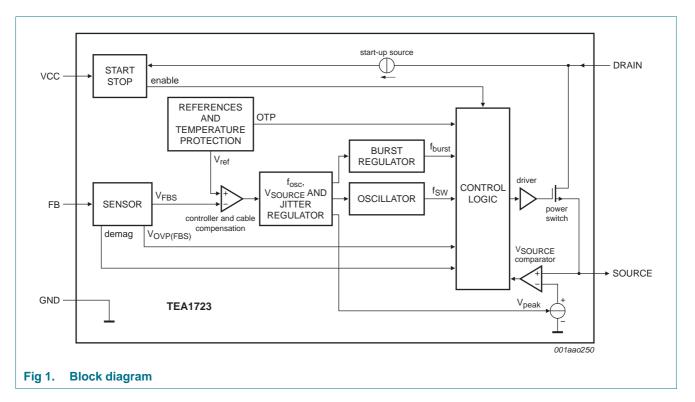
#### Table 1.Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Power swit	ch (Pin: DRAIN)					
R <sub>DSon</sub>	drain-source on-state resistance	I <sub>ds</sub> = 30 mA; T <sub>j</sub> = 25 °C	3.5	4.8	6	Ω
Oscillator (	Pins: DRAIN and S	SOURCE)				
f <sub>burst</sub>	burst frequency	burst frequency in CVB mode, without jitter	1575	1750	1925	Hz
f <sub>osc-high</sub>	oscillator frequency High	maximum switching frequency in CV and CC mode, without jitter	48	50.5	53	kHz
Supply (Pir	n: VCC)					
V <sub>CC(startup)</sub>	start-up supply voltage		15	17	19	V
V <sub>CC(stop)</sub>	stop supply voltage	undervoltage lockout of IC	7.5	8.5	9.5	V

# 2. Ordering information

Table 2. Ordering	information		
Type number	Package		
	Name	Description	Version
TEA1723FT/N1	SO7	plastic small outline package; 7 leads; body width 3.9 mm	SOT1175-1

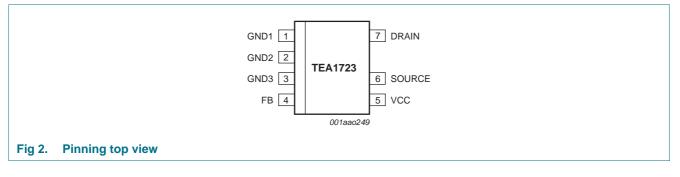
# 3. Block diagram



## 3.1 Block diagram

# 4. Pinning information

## 4.1 Pinning



### 4.2 Pin description

Pin	Pin name	I/O type	Pin description
1	GND1		ground
2	GND2		ground
3	GND3		ground
4	FB	I	feedback input for voltage sensing
5	VCC	I	supply input
6	SOURCE	0	source for power switch
7	DRAIN	I	drain of power switch
-	-		high voltage spacer

## 5. Functional description

### 5.1 Start-up

The TEA1723 starts up by charging the VCC capacitor until the V<sub>CC(start)</sub> level. The charging current flows from the high voltage DRAIN pin via an internal start-up current source to the VCC pin.

Once the start level has been reached the start-up current source is switched off. During switching operation, the start-up current source remains current-less and has zero bleeder loss.

### 5.2 Primary sensing

The FB input senses the reflected secondary voltage on the primary side. The FB input has a sample and hold function that samples the FB voltage on the secondary stroke to control the output voltage.

The sampled  $V_{\text{FBS}}$  voltage is the input for the TEA1723's control loop and defines the operating mode.

### 5.3 Operating modes

The TEA1723 operates in three modes, one of which is active at the time. The three modes in order of decreasing load impedance are:

- CVB: Constant Voltage with Burst mode
- CV: Constant Voltage mode
- CC: Constant Current mode

The converter acts as a voltage source in CVB and CV modes.

The converter acts as a current source in CC mode.

#### 5.3.1 Constant Voltage with Burst mode (CVB)

At low power, the TEA1723 operates in Burst mode.

Burst mode operates with a  $V_{SOURCE}$  = 100 mV, a switching frequency of 22.5 kHz and burst duty-cycle regulation by sensing the FB voltage.

The TEA1723 features an energy save function that puts the main part of the analogue blocks in a sleep mode with low supply current in burst mode. The burst mode enables the energy save mode in the non-switching part of the burst. The IC switches to the nominal supply just before new burst starts.

Transition from burst mode to CV mode happens at 100 % burst duty cycle: a burst completely filled with 32 pulses. This 100 % pulse train is identical to the lowest power level of the CV mode. The TEA1723 changes directly from burst mode to CV mode if the FB voltage drops below 2.4 V in burst mode.

### 5.3.2 Constant Voltage mode (CV)

At higher power levels, the TEA1723 operates in CV mode. The output voltage is sensed by the FB pin and the control keeps the output voltage constant over the power range.

CV mode starts at 22.5 kHz switching frequency and  $I_{\text{SOURCE}}$  regulation at the  $V_{\text{SOURCE}}$  minimum level of 100 mV.

With an increasing power output, the  $V_{\mbox{SOURCE}}$  level and the switching frequency are also increased.

CV mode is exited when the maximum power level is reached. Maximum power occurs at  $I_{SOURCE}$  regulation at the  $V_{SOURCE}$  maximum level of 555 mV and a maximum switching frequency of 50.5 kHz.

### 5.3.3 Constant Current mode (CC)

The CC mode starts at maximum power delivery and keeps the output current constant for decreasing output voltage.

CC mode is enabled when the converter is operating at the maximum switching frequency, with the maximum primary peak current when the FB voltage drops below the regulated level.

CC mode operation controlled is by regulation of the switching frequency from 50.5 kHz down to 22.5 kHz and by I<sub>SOURCE</sub> regulation from the maximum V<sub>SOURCE</sub> level of 555 mV until level of V<sub>SOURCE</sub> is 0.21 V. The V<sub>SOURCE</sub> level of 0.21 V equals the level at start-up with zero output voltage and the output capacitor discharged or on a short-circuit of the charger output.

### 5.4 Jitter

The TEA1723 features a jitter function for ElectroMagnetic Interference (EMI) reduction. The switching frequency is 7 % typical for the spread spectrum. The sweep frequency is a low frequency of approximately 200 Hz. To keep the output power constant, the V<sub>SOURCE</sub> level is jittered with the opposite polarity. The jitter is active in all operation modes except burst mode.

HV start-up flyback controller with integrated MOSFET for 11 W

# 6. Limiting values

#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
T <sub>amb</sub>	ambient temperature			-40	+85	°C
Т <sub>ј</sub>	junction temperature			-40	+150	°C
T <sub>stg</sub>	storage temperature			-55	+150	°C
V <sub>ESD</sub>	electrostatic discharge voltage	CDM; all pins		-500	+500	V
		HBM; all pins, except pin 7	<u>[1]</u>	-2000	+2000	V
		HBM; pin 7	<u>[1]</u>	-1000	+1000	V
Voltages						
V <sub>DRAIN</sub>	voltage on pin DRAIN			-2	+700	V
V <sub>SOURCE</sub>	voltage on pin SOURCE			-0.3	+5	V
V <sub>CC</sub>	voltage on pin VCC			-0.3	+35	V
V <sub>FB</sub>	voltage on pin FB			-20	+5	V
Currents						
I <sub>DRAIN</sub>	current on pin DRAIN			-0.1	+1.5	А
ISOURCE	current on pin SOURCE			-1.5	+0.1	А

[1] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

# 7. Thermal characteristics

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
from	thermal resistance from junction to	in free air; SO7 package; on open PCB of 2.2 cm X 2.2 cm; 2-layer; 70 μm Cu	-	136	-	K/W
	ambient	in free air; SO7 package; on open PCB of 3 cm X 6 cm; 1-layer; 35 µm Cu operating charger	-	136	-	K/W

# 8. Characteristics

### Table 5.Characteristics

 $V_{CC} = 20 V$ ;  $V_{FB} = 0 V$ ;  $R_{source} = 0.75 \Omega$ ;  $T_{j-switch} = 25 °C$ ;  $T_{j-controller} = 25 °C$ ; all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

		Conditions	Min	Тур		Unit
Supply (Pin: V	(CC)					
I <sub>CC(startup)0V</sub>	start-up supply current	$V_{CC} = 0 V$	-1.6	-1.2	-0.8	mA
I <sub>CC(startup)17V</sub>	start-up supply current	V <sub>CC</sub> = V <sub>CC(startup)</sub>	-1.6	-0.7	-0.2	mA
I <sub>CC(energysave)</sub>	supply current in energy save	$V_{FB}$ = 2.8 V, non-switching	90	130	170	μA
I <sub>CC(50kHz)</sub>	supply current at 50 kHz	in CC mode	530	750	970	μΑ
V <sub>CC(startup)</sub>	start-up supply voltage		15	17	19	V
V <sub>CC(stop)</sub>	stop supply voltage	undervoltage lockout of IC	7.5	8.5	9.5	V
T <sub>otp</sub>	overtemperature protection threshold temperature on controller die		-	150	-	°C
T <sub>otp(hys)</sub>	overtemperature protection temperature hysteresis		-	50	-	°C
Feedback (Pin	: FB)					
V <sub>th(ovp)fbck</sub>	feedback overvoltage protection threshold voltage		3.1	3.2	3.3	V
V <sub>ref(fbck)</sub>	feedback reference voltage	in CV ode	2.5	2.55	2.6	V
V <sub>th(fbck)</sub> CV	constant voltage mode feedback threshold voltage	in burst mode operation	2.35	2.4	2.45	V
Vth(det)demag(fb)	demagnetization detection voltage level on FB pin		25	50	75	mV
Oscillator (Pin	s: DRAIN and SOURCE)					
f <sub>burst</sub>	burst frequency	burst frequency in CVB mode, without jitter	1575	1750	1935	Hz
f <sub>jit</sub> /f <sub>sw</sub>	jitter frequency to switching frequency ratio	in all operation modes except in CVB mode	5	7	9	%
f <sub>osc-high</sub>	oscillator frequency High	maximum switching frequency in CV and CC mode, without jitter	48	50.5	53	kHz
f <sub>osc-low</sub>	oscillator frequency Low	minimum switching frequency in CV and CC mode, without jitter. Switching frequency in CVB mode	21	22.5	24	kHz
f <sub>sweep</sub>	jitter sweep frequency		-	200	-	Hz
δ <sub>max</sub>	maximum duty cycle		72	75	78	%

TEA1723FT Product data sheet

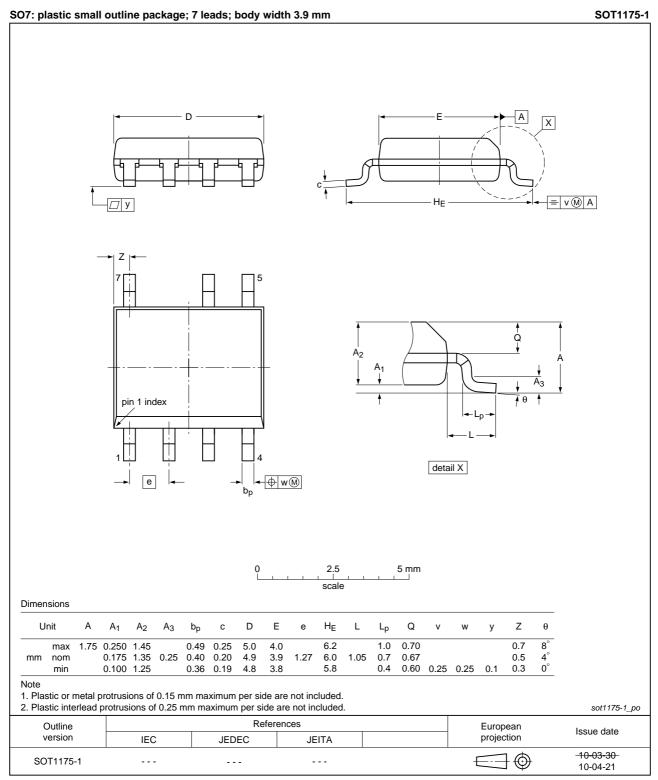
#### Table 5. Characteristics ...continued

 $V_{CC} = 20 V$ ;  $V_{FB} = 0 V$ ;  $R_{source} = 0.75 \Omega$ ;  $T_{j-switch} = 25 °C$ ;  $T_{j-controller} = 25 °C$ ; all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Parameter	Conditions	Min	Тур	Max	Unit
(Pin: DRAIN)					
off-state drain current	V <sub>DRAIN</sub> = 325 V	-	1	-	μA
drain-source on-state resistance	T <sub>j</sub> = 25 °C; I <sub>ds</sub> = 30 mA	3.5	4.8	6	Ω
drain-source breakdown voltage		700	-	-	V
omparator (Pin: SOURC	E)				
propagation delay time	dV/dt = 0.2 V/µs	-	100	-	ns
leading edge blanking time		290	325	360	ns
reference voltage, high peak voltage	maximum peak voltage in CV and CC modes, without jitter	0.525	0.555	0.585	V
reference voltage, low peak voltage	in CVB mode	0.085	0.1	0.115	V
reference voltage at start-up or 0 V feedback voltage	in CC mode with $V_{FBS} = 0 V$	0.18	0.21	0.24	V
	(Pin: DRAIN) off-state drain current drain-source on-state resistance drain-source breakdown voltage comparator (Pin: SOURC propagation delay time leading edge blanking time reference voltage, high peak voltage reference voltage, low peak voltage reference voltage at start-up or 0 V	(Pin: DRAIN)off-state drain current $V_{DRAIN} = 325 \text{ V}$ drain-source on-state resistance $T_j = 25 \text{ °C}; I_{ds} = 30 \text{ mA}$ drain-source breakdown voltagedrain-sourcecomparator (Pin: SOURCE)propagation delay time $dV/dt = 0.2 \text{ V/}\mu\text{s}$ leading edge blanking timemaximum peak voltage in CV and CC modes, without jitterreference voltage, high peak voltagein CVB modereference voltage, low peak voltagein CC mode with V_{FBS} = 0 V	(Pin: DRAIN)·off-state drain current $V_{DRAIN} = 325 \ V$ -drain-source on-state $T_j = 25 \ ^{\circ}C; \ I_{ds} = 30 \ mA$ 3.5drain-source $T_j = 25 \ ^{\circ}C; \ I_{ds} = 30 \ mA$ 700breakdown voltage700comparator (Pin: SOURCE)700propagation delay time $dV/dt = 0.2 \ V/\mu$ s-leading edge blanking time290reference voltage, high peak voltagemaximum peak voltage in CV and CC modes, without jitter0.525reference voltage, low peak voltagein CVB mode in CVB mode0.085reference voltage at start-up or 0 Vin CC mode with V_{FBS} = 0 \ V0.18	(Pin: DRAIN)off-state drain current $V_{DRAIN} = 325 \ V$ -1drain-source on-state resistance $T_j = 25 \ ^{\circ}C; \ I_{ds} = 30 \ mA$ 3.54.8drain-source breakdown voltage700-comparator (Pin: SOURCE)700-propagation delay timedV/dt = 0.2 V/µs-100leading edge blanking time290325reference voltage, high peak voltagemaximum peak voltage in CV and CC modes, without jitter0.5250.555reference voltage, low peak voltagein CVB mode0.0850.1reference voltage at start-up or 0 Vin CC mode with V_{FBS} = 0 V0.180.21	(Pin: DRAIN)off-state drain current $V_{DRAIN} = 325 \ V$ -1-drain-source on-state resistance $T_j = 25 \ ^{\circ}C; \ I_{ds} = 30 \ mA$ 3.54.86drain-source breakdown voltage700comparator (Pin: SOURCE)700propagation delay timedV/dt = 0.2 V/µs-100-leading edge blanking time290325360reference voltage, high peak voltagemaximum peak voltage in CV and CC modes, without jitter0.5250.5550.585reference voltage, low peak voltagein CVB mode0.0850.10.115reference voltage at start-up or 0 Vin CC mode with V <sub>FBS</sub> = 0 V0.180.210.24

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## 9. Package outline



### Fig 3.Package outline SOT1175-1 (SO7)

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TEA1723FT

# **10. Revision history**

Document IDRelease dateData sheet statusChange noticeSupersedesTEA1723FT v.2.120120607Product data sheet-TEA1723FT v.2Modifications:• Symbol t <sub>d(OCP)</sub> changed to t <sub>PD</sub> in table 5 on page 8. • Data sheet title changedTEA1723FT v.2TEA1723FT v.220120508Product data sheet-TEA1723FT v.1TEA1723FT v.120120127Preliminary data sheet	Table 6. Revision	history			
Modifications:       • Symbol t <sub>d(OCP)</sub> changed to t <sub>PD</sub> in table <u>5 on page 8</u> .         • Data sheet title changed.         TEA1723FT v.2       20120508       Product data sheet -       TEA1723FT v.1	Document ID	Release date	Data sheet status	Change notice	Supersedes
Data sheet title changed.  TEA1723FT v.2 20120508 Product data sheet TEA1723FT v.1	TEA1723FT v.2.1	20120607	Product data sheet	-	TEA1723FT v.2
	Modifications:		/ -	<u>n page 8</u> .	
TEA1723FT v.1 20120127 Preliminary data sheet	TEA1723FT v.2	20120508	Product data sheet	-	TEA1723FT v.1
	TEA1723FT v.1	20120127	Preliminary data shee	t -	-

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Document status[1] [2]	Product status <sup>[3]</sup>	Definition
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### 13. Contents

1	Product profile1
1.1	General description1
1.2	Features and benefits1
1.3	Applications2
1.4	Quick reference data2
2	Ordering information3
3	Block diagram
3.1	Block diagram
4	Pinning information4
4.1	Pinning
4.2	Pin description4
1	Product profile1
5.1	Start-up
5.2	Primary sensing4
5.3	Operating modes5
5.4	Jitter
5.3.1	Constant Voltage with Burst mode (CVB)5
5.3.2	Constant Voltage mode (CV)5
5.3.3	Constant Current mode (CC)6
6	Limiting values7
7	Thermal characteristics7
8	Characteristics8
9	Package outline10
10	Revision history11
11	Legal information12
11.1	Data sheet status12
11.2	Definitions12
11.3	Disclaimers
11.4	Trademarks13
12	Contact information13

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